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				Examiner Name	Kenneth Parker Deo]
Sheet	1	of	3	Attorney Docket Number	0756-7224	

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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 3 Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. Applicant is to place a check mark here if English language Translation is attached.

^{*}Unique citation designation number. * Applicant is to place a check mark here if English language Translation is attached.

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Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number. Complete If Known Substitute for form 1449A/PTO Based on 09/356,376 70/724,126 Application Number INFORMATION DISCLOSURE July 19, 1999 12/1/03 Filing Date STATEMENT BY APPLICANT Hongyong ZHANG et al. First Named Inventor (use as many sheets as necessary) Group Art Unit Kenneth Parker Examiner Name œſ 3 2 Attorney Docket Number 0756-7224

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